



A Product Line of **Diodes Incorporated**



FMMT619

50V NPN SILICON LOW SATURATION TRANSISTOR IN SOT23

Features and Benefits

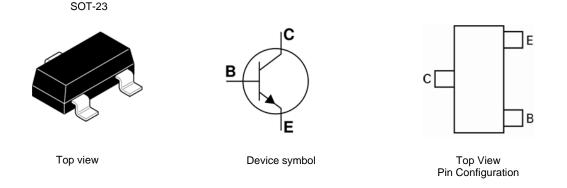
- BV_{CEO} > 50V •
- I_C = 2A Continuous Collector Current •
- Low Saturation Voltage V_{CE(sat)} < 200mV @ 1A •
- $R_{SAT} = 68m\Omega$ for a low equivalent on-resistance •
- hFE characterised up to 6A for high current gain hold-up
- 625mW power dissipation due to SuperSOT package .
- Complementary NPN type: FMMT720
- "Lead-Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT-23 •
- Case material: Molded Plastic. "Green" Molding Compound (Note 2) UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Copper plated Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (Approximate)

Applications

- MOSFET Gate Driving
- DC-DC / DC-AC Converters
- Regulator
- LED driver
- Motor Control



Ordering Information

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT619TA (Note 3)	619	7	8	3,000
FMMT619TC (Note 3)	619	13	8	10,000

1. No purposefully added lead.

Diodes Inc's "Green" Policy can be found on our website at https://www.diodes.com/
Devices with lot number starting from PID0155145 (March 2010) are "Green" products.

Marking Information

Notes:







Maximum Ratings @TA = 25°C unless otherwise specified

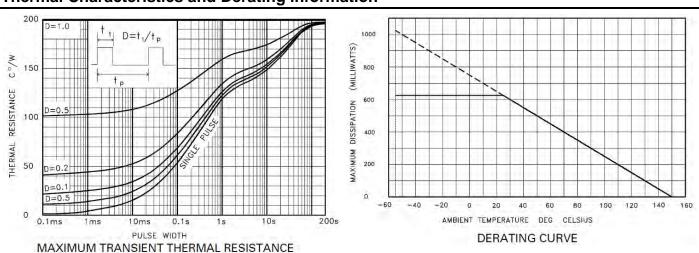
Characteristic		Symbol	Value	Unit
Collector-Base Voltage		V _{CBO}	50	V
Collector-Emitter Voltage		V _{CEO}	50	V
Emitter-Base Voltage		V _{EBO}	5	V
Continuous Collector Current	(Note 4)	Ic	2	A
Peak Pulse Current		I _{CM}	6	A
Base Current		IB	500	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 4)	Р	625	mW
Linear Rating Factor	(NOLE 4)	PD	5	mW/°C
Thermal Resistance, Junction to Ambient (Note 4)		R _{0JA}	200	°C/W
Thermal Resistance, Junction to Lead	(Note 5)	R _{θJL}	194	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

4. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured Notes: when operating in a steady-state condition.

5. Thermal resistance from junction to solder-point (at the end of the collector lead).



Thermal Characteristics and Derating information





Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS	Symbol	WIIII	тур	IVIAX	Unit	Test condition
Collector-Base Breakdown Voltage	BV _{CBO}	50	190	L .	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 6)	BVCBO	50	65		V	$I_{\rm C} = 10 \text{mA}$
Emitter-Base Breakdown Voltage	BVCEO BVEBO	5	8.3		V	$I_E = 100 \mu A$
Collector Cut-off Current	I _{CBO}	-		100	nA	$V_{CB} = 40V$
Emitter Cut-off Current	IEBO		-	100	nA	$V_{EB} = 4V$
Collector Emitter Cut-off Current	I _{CES}	-	-	100	nA	$V_{\text{EB}} = 40V$
ON CHARACTERISTICS (Note 6)	·CE3					VCE3 - 10 V
Static Forward Current Transfer Ratio	hfe	200 300 200 100	400 450 400 225 40	- - - -	-	$\label{eq:linear} \begin{array}{l} I_{C} = 10 \text{mA}, \ V_{CE} = 2 \text{V} \\ I_{C} = 200 \text{mA}, \ V_{CE} = 2 \text{V} \\ I_{C} = 1 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} = 2 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} = 6 \text{A}, \ V_{CE} = 2 \text{V} \end{array}$
Collector-Emitter Saturation Voltage	V _{CE(sat)}		10 125 150	20 200 220	mV	$\begin{split} I_{C} &= 0.1A, \ I_{B} = 10 mA \\ I_{C} &= 1A, \ I_{B} = 10 mA \\ I_{C} &= 2A, \ I_{B} = 50 mA \end{split}$
Base-Emitter Saturation Voltage	V _{BE(sat)}	-	0.87	1.0	V	$I_{\rm C} = 2A, I_{\rm B} = 50 {\rm mA}$
Base-Emitter Saturation Voltage	V _{BE(on)}	-	0.80	1.0	V	$I_{C} = 2A, V_{CE} = 2V$
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f _T	100	165	-	MHz	I _C = 50mA, V _{CE} = 10V, f = 100MHz
Collector Output Capacitance	C _{obo}	-	12	20	pF	V _{CB} = 10V, f = 1MHz
Turn-On Time	t _(on)	-	170	-	ns	$V_{CC} = 10V, I_C = 1A,$
Turn-Off Time	t _(off)	-	750	-	ns	$I_{B1} = -I_{B2} = 10 \text{mA}$

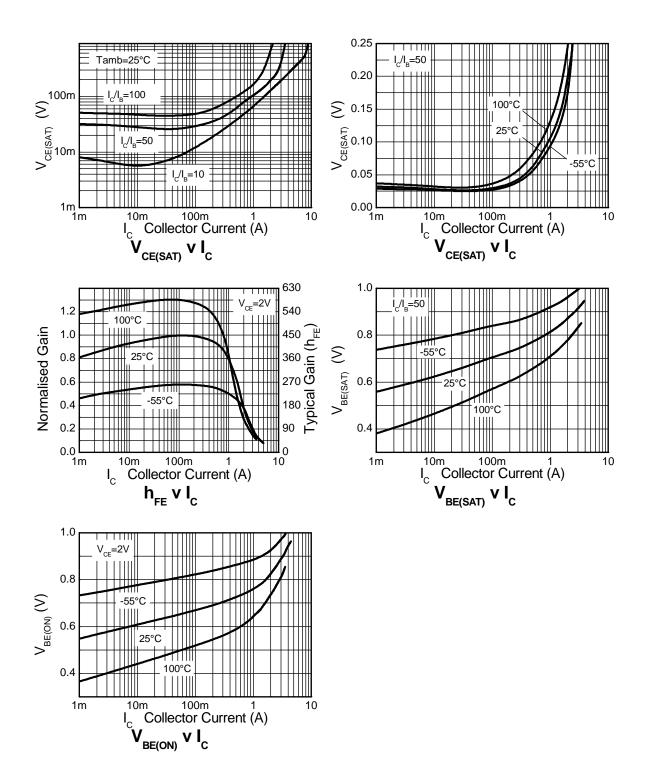
Notes: 6. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%







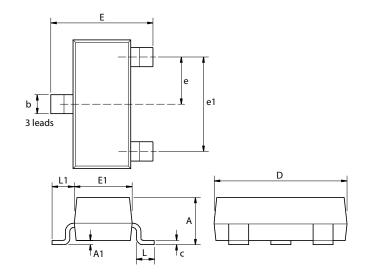
Typical Electrical Characteristics







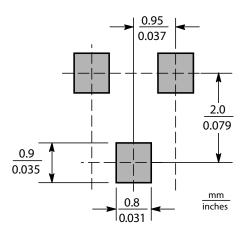
Package Outline Dimensions



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
А	-	1.12	-	0.044	e1	1.90 NOM		0.075 NOM	
A1	0.01	0.10	0.0004	0.004	E	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
с	0.085	0.20	0.003	0.008	L	0.25	0.60	0.0098	0.0236
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
е	0.95	NOM	0.037	NOM	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

Suggested Pad Layout







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